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DATE: May 6, 2003

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PTO IDENTIFIER:

Application Number 09/387,857-Conf. #3099

Patent Number

Inventor: Fumitaka Sugaya

MESSAGE TO:

C. Novacek

FAX NUMBER:

(703) 872-9318

FROM:

CONNOLLY BOVE LODGE & HUTZ LLP

George R. Pettit

PHONE:

(202) 331-7111

Attorney Dkt. #:

21776-00039-US

PAGES (including Cover Sheet):

11

CONTENTS:

In response to the Office Action mailed February 6, 2003, Applicant wish to file the attached Amendment.

If your receipt of this transmission is in error, please notify this firm immediately by collect call to (202) 331-7111 and send the original transmission to us by return mail at the address below.

CONNOLLY BOVE LODGE & HUTZ LLP 1990 M Street, N.W., Suite 800, Washington, DC 20036-3425

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P.02/11

PTO/SB/97 (12-97)
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on <u>May 6, 2003</u> Date

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Deborah A. Harrell

Typed or printed name of person signing Certificate

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must Identify each submitted paper.

Amendment in Response to Non-Final Office Action;

Amendment; and

Amendment Transmittal.

AMENDMENT TRANSMITTAL LETTER Docket No. 21776-00039-US								7
Application No. 09/387,857-Conf. #3099			Filing Date September 1, 1999		Examiner C. Novacek		Art Unit 2822	
Applicant(s): Furnitaka Sugaya								
Invention: A SEMICONDUCTOR DEVICE AND A METHOD OF MANUFACTURING THE SAME								
TO THE COMMISSIONER FOR PATENTS Transmitted herewith is an amendment in the above-identified application.								
The fee has been calculated and is transmitted as shown below.								
	CLAIMS AS AMENDED Claims Highest							
		Remaining After	Number Previously	Number Extra Claims				
	Total Claims	Amendment 18	- 20 =	Present	Rate X		0.00	
	Independent Claims	5	- 5 =	0	×		0.00	
Multiple Dependent Claims (check if applicable) Other fee (please specify):								
	TOTAL ADDITIONAL FEE FOR THIS AMENDMENT: X Large Entity O.00 FAX RECEI							
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No additional fee is required for this amendment.								pnn3
Please charge Deposit Account No in the amount of \$ A duplicate copy of this sheet is enclosed TECHNOLOGY CENT								
[A check in the amount of \$ to cover the filing fee is enclosed.							
Payment by credit card. Form PTO-2038 is attached.								
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x Charge any additional filing or application processing fees required under 37 CFR 1.16 and 1.17.								
Dated: May 6, 2003								
George R. Pettit Attorney Reg. No.: 27,369								
CONNOLLY BOVE LODGE & HUTZ LLP 1990 M Street, N.W., Suite 800								
Washington, DC 20036-3425 (202) 331-7111								
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Dated: May 6, 2003 Signature: Color (Deborah A. Harrell)								

shown below.
Dated: May 6, 2003

2022936229 P.04/11

17/E DICING 5-7-03

Docket No.: 21776-00039-US

(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Fumitaka Sugaya

Application No.: 09/387,857

Group Art Unit: 2822

Filed: September 1, 1999

Examiner: C. Novacek

For: A SEMICONDUCTOR DEVICE AND A

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METHOD OF MANUFACTURING THE SAME

AMENDMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450 **FAX RECEIVED**

MAY 0 6 2003

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Dear Sir:

In response to the Office Action dated February 6, 2003 (Paper No. 16), please amend the above-identified U.S. patent application as follows:

IN THE CLAIMS:

Kindly amend the claims as follows:

32. (Amended) A method of fabricating a semiconductor device, comprising: the first step of defining an element active region by forming an element isolation structure on a semiconductor substrate:

the second step of forming a gate insulating film and a gate electrode in said element active region;

the third step of doping an impurity into said active region of said substrate to form a pair of impurity diffusion layers in surface regions of said semiconductor substrate on two sides of said gate electrode;